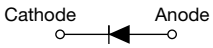
Ultrafast Soft Recovery Diode, 150 A FRED Pt®



PowerTab®



FEATURES

- Ultrafast recovery time
- 175 °C max. operating junction temperature
- Screw mounting only
- AEC-Q101 qualified
- PowerTab® package
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Pb-free

e4

RoHS COMPLIANT

BENEFITS

- Reduced RFI and EMI
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION/APPLICATIONS

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems.
The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	150 A
V_R	200 V
V_F at I_F	0.77 V
t_{rr} (typ.)	See recovery table
T_J max.	175 °C
Package	PowerTab®
Circuit configuration	Single

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Cathode to anode voltage	V_R		200	V
Continuous forward current	$I_{F(AV)}$	T_C = 116 °C	150	A
Single pulse forward current	I_{FSM}	T_C = 25 °C	1600	
Maximum repetitive forward current	I_{FRM}	Square wave, 20 kHz	380	
Operating junction and storage temperatures	T_J, T_{Stg}		-55 to +175	°C

ELECTRICAL SPECIFICATIONS (T_J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR}, V_R	I_R = 100 µA	200	-	-	V
Forward voltage	V_F	I_F = 150 A	-	0.94	1.10	
		I_F = 150 A, T_J = 175 °C	-	0.77	0.88	
Reverse leakage current	I_R	V_R = V_R rated	-	-	50	µA
		T_J = 150 °C, V_R = V_R rated	-	-	2	mA
Junction capacitance	C_T	V_R = 200 V	-	180	-	pF
Series inductance	L_S	Measured lead to lead 5 mm from package body	-	3.5	-	nH

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DYNAMIC RECOVERY CHARACTERISTICS (T_J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t_{rr}	T_J = 25 °C	I_F = 150 A V_R = 160 V dI_F/dt = 200 A/µs	-	48	-	ns
		T_J = 125 °C		-	88	-	
Peak recovery current	I_{RRM}	T_J = 25 °C		-	5	-	A
		T_J = 125 °C		-	12	-	
Reverse recovery charge	Q_{rr}	T_J = 25 °C		-	120	-	nC
		T_J = 125 °C		-	520	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction to case	R_{thJC}		-	-	0.35	K/W
Thermal resistance, case to heatsink	R_{thCS}	Mounting surface, flat, smooth and greased	-	0.2	-	
Weight			-	-	5.02	g
			-	0.18	-	oz.
Mounting torque			1.2 (10)	-	2.4 (20)	N · m (lbf · in)
Marking device		Case style PowerTab®	150EBU02H			

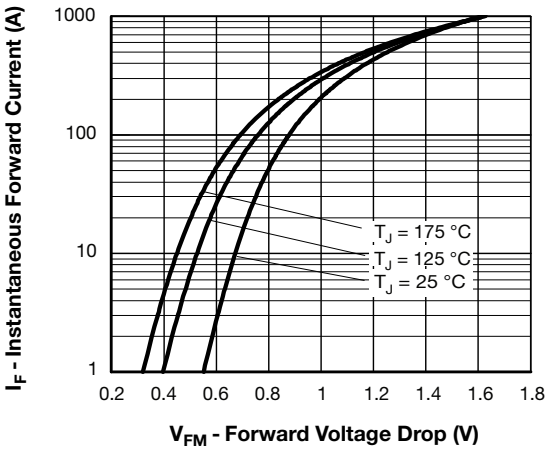


Fig. 1 - Maximum Forward Voltage Drop Characteristics

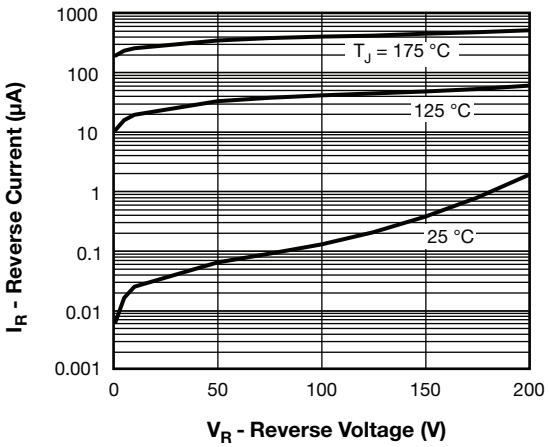


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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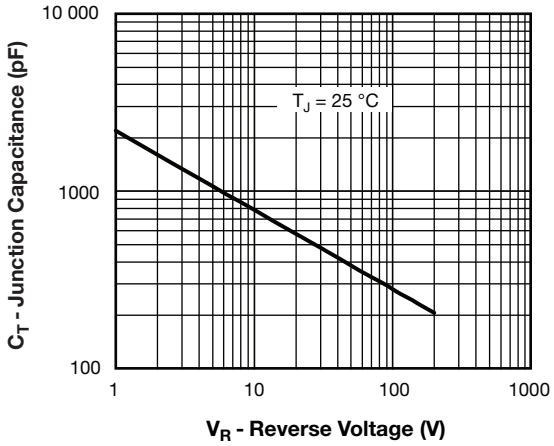


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

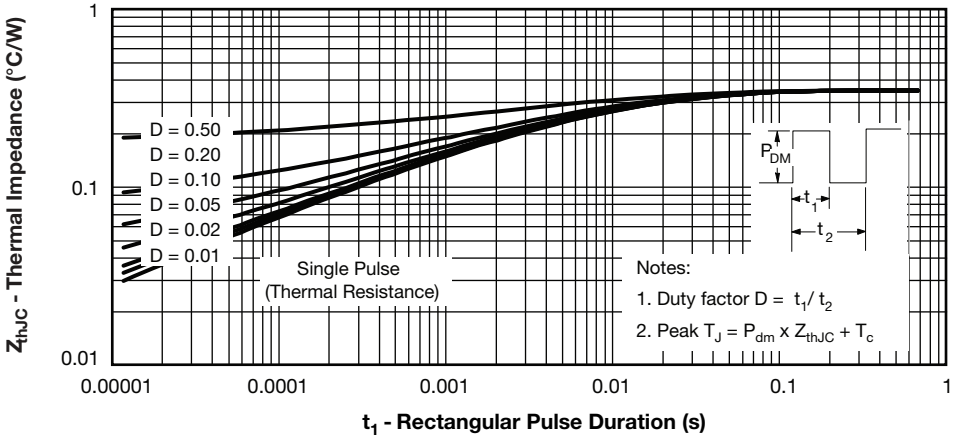


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

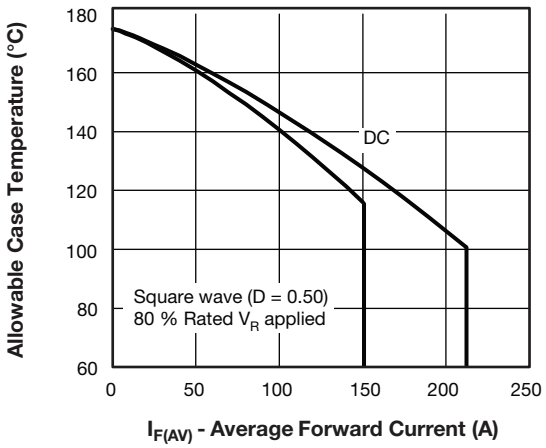


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

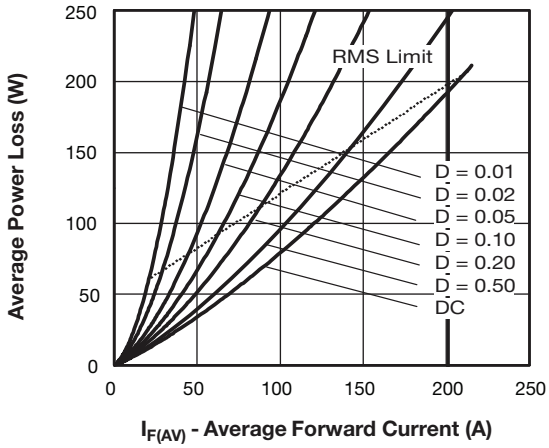


Fig. 6 - Forward Power Loss Characteristics

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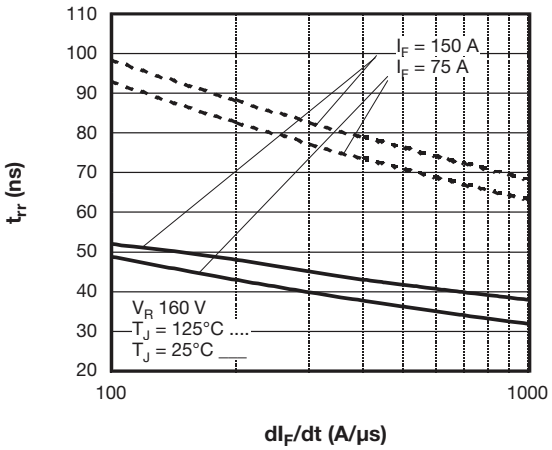


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

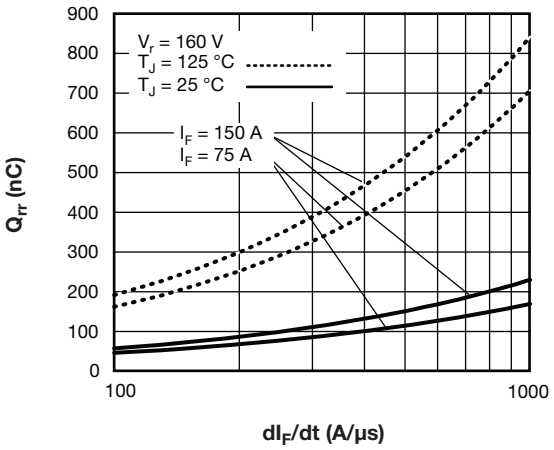
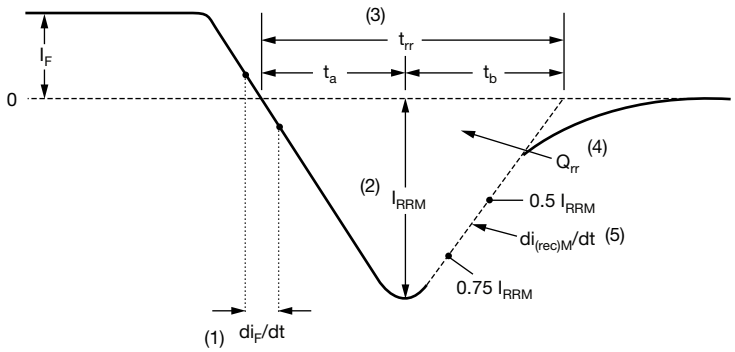


Fig. 8 - Typical Stored Charge vs. dI_F/dt



(1) di_F/dt - rate of change of current through zero crossing

(2) I_{RRM} - peak reverse recovery current

(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

(4) Q_{rr} - area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

Device code

VS-	150	E	B	U	02	H	F4
1	2	3	4	5	6	7	8

1 - Vishay Semiconductors product
2 - Current rating (150 = 150 A)
3 - Single diode
4 - PowerTab®
5 - Ultrafast recovery
6 - Voltage rating (02 = 200 V)
7 - H = AEC-Q101 qualified
8 - F4 = RoHS-compliant and totally lead (Pb)-free

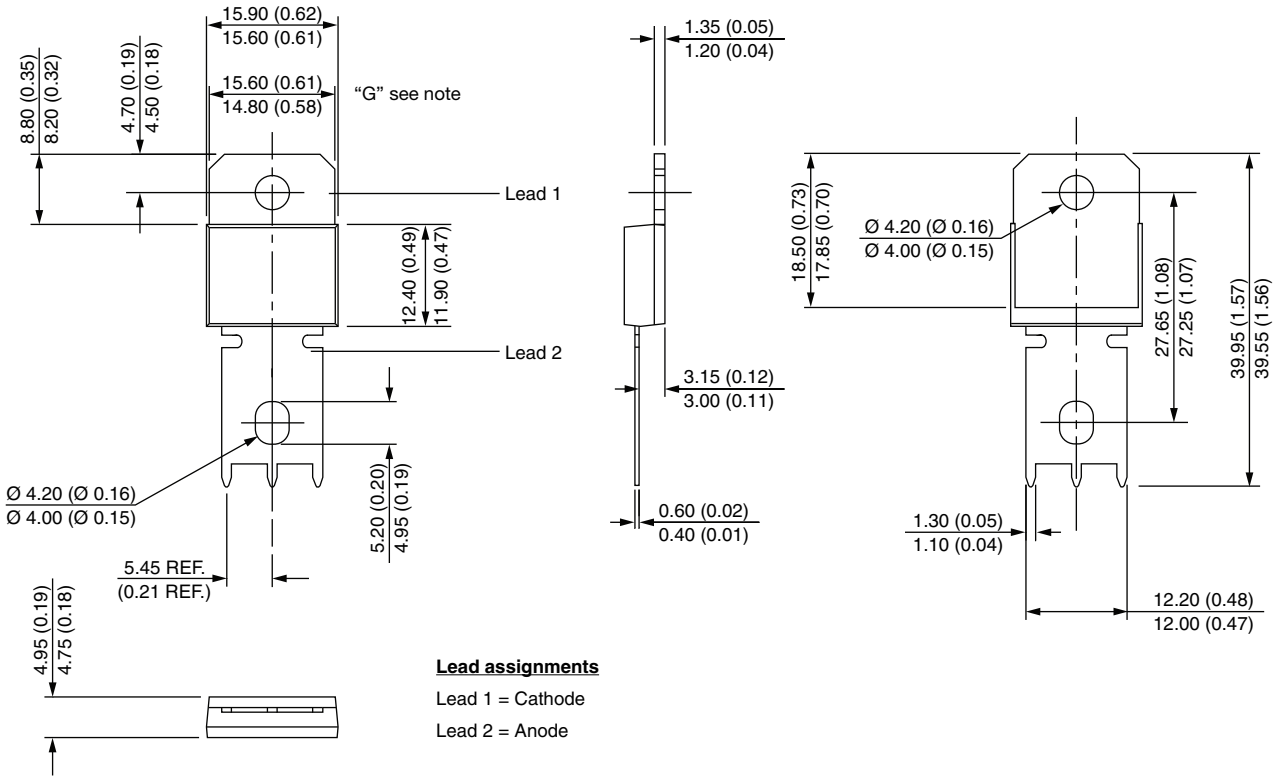
ORDERING INFORMATION (Example)			
PREFERRED P/N	**QUANTITY PER T/R**	**MINIMUM ORDER QUANTITY**	**PACKAGING DESCRIPTION**
VS-150EBU02HF4	25	375	Antistatic plastic tube

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95240
Part marking information	www.vishay.com/doc?95467
Application note	www.vishay.com/doc?95179
SPICE model	www.vishay.com/doc?96503

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PowerTab®

DIMENSIONS in millimeters (inches)



Lead assignments

Lead 1 = Cathode

Lead 2 = Anode

Note:
Outline conform to JEDEC® TO-275, except for dimension "G" only

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